

CAT5115

32-Tap Digitally Programmable Potentiometer (DPP™)

LEAD EREE IM

FEATURES

- 32-position, linear-taper potentiometer
- Low power CMOS technology
- Single supply operation: 2.5V-5.5V
- Increment up/down serial interface
- Resistance values: $10k\Omega$. $50k\Omega$ and $100k\Omega$
- Available in PDIP, SOIC, TSSOP and MSOP packages

APPLICATIONS

- Automated product calibration
- Remote control adjustments
- Offset, gain and zero control
- Tamper-proof calibrations
- Contrast, brightness and volume controls
- Motor controls and feedback systems
- Programmable analog functions

DESCRIPTION

The CAT5115 is a single digitally programmable potentiometer (DPP™) designed as a electronic replacement for mechanical potentiometers and trim pots. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

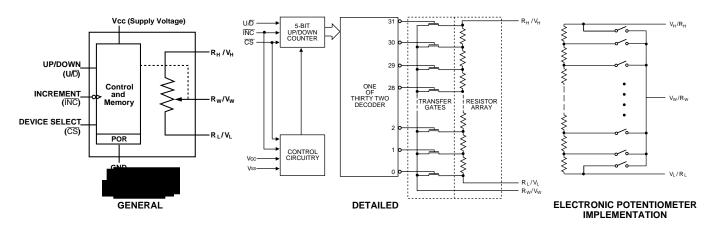
The CAT5115 contains a 32-tap series resistor array connected between two terminals R_H and R_L . An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper, R_W . The wiper is always set to the mid point, tap 15 at power up. The tap position is not stored in memory. Wiper-control of the CAT5115 is accomplished with three input control pins, \overline{CS} , U/\overline{D} , and \overline{INC} . The \overline{INC} input increments the wiper in the direction which is

determined by the logic state of the U/\overline{D} input. The \overline{CS} input is used to select the device.

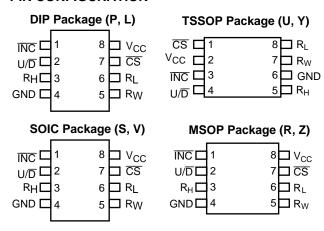
The digitally programmable potentiometer can be used as a three-terminal resistive divider or as a two-terminal variable resistor. DPPs bring variability and programmability to a wide variety of applications including control, parameter adjustments, and signal processing.

For a pin-compatible device that recalls a stored tap position on power-up refer to the CAT5114 data sheet.

FUNCTIONAL DIAGRAM



PIN CONFIGURATION



PIN DESCRIPTIONS

INC: Increment Control Input

The \overline{INC} input moves the wiper in the up or down direction determined by the condition of the U/ \overline{D} input.

U/D: Up/Down Control Input

The U/ \overline{D} input controls the direction of the wiper movement. When in a high state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment toward the R_H terminal. When in a low state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment towards the R_L terminal.

RH: High End Potentiometer Terminal

 R_{H} is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the R_{L} terminal. Voltage applied to the R_{H} terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND.

Rw: Wiper Potentiometer Terminal

 R_W is the wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs, \overline{INC} , U/\overline{D} and \overline{CS} . Voltage applied to the R_W terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND.

RL: Low End Potentiometer Terminal

 R_{L} is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the R_{H} terminal. Voltage applied to the R_{L} terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND. R_{L} and R_{H} are electrically interchangeable.

PIN FUNCTIONS

Pin Name	Function		
ĪNC	Increment Control		
U/D	Up/Down Control		
RH	Potentiometer High Terminal		
GND	Ground		
Rw	Potentiometer Wiper Terminal		
RL	Potentiometer Low Terminal		
CS	Chip Select		
V _{CC}	Supply Voltage		

CS: Chip Select

The chip select input is used to activate the control input of the CAT5115 and is active low. When in a high state, activity on the $\overline{\text{INC}}$ and U/D inputs will not affect or change the position of the wiper.

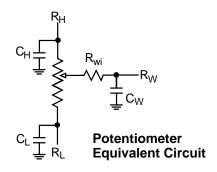
DEVICE OPERATION

The CAT5115 operates like a digitally controlled potentiometer with R_{H} and R_{L} equivalent to the high and low terminals and R_{W} equivalent to the mechanical potentiometer's wiper. There are 32 available tap positions including the resistor end points, R_{H} and R_{L} . There are 31 resistor elements connected in series between the R_{H} and R_{L} terminals. The wiper terminal is connected to one of the 32 taps and controlled by three inputs, \overline{INC} , U/\overline{D} and \overline{CS} . These inputs control a five-bit up/down counter whose output is decoded to select the wiper position.

With $\overline{\text{CS}}$ set LOW the CAT5115 is selected and will respond to the U/ $\overline{\text{D}}$ and $\overline{\text{INC}}$ inputs. HIGH to LOW transitions on $\overline{\text{INC}}$ will increment or decrement the wiper (depending on the state of the U/ $\overline{\text{D}}$ input and five-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. When the CAT5115 is powered-down, the wiper position is reset. When power is restored, the counter is set to the mid point, tap 15.

OPERATION MODES

ĪNC	CS	U/D	Operation
High to Low	Low	High	Wiper toward H
High to Low	Low	Low	Wiper toward L
X	High	Х	Standby



ABSOLUTE MAXIMUM RATINGS

Supply Voltage	
V _{CC} to GND	0.5V to +7V
Inputs	
CS to GND	0.5V to V_{CC} +0.5V
INC to GND	0.5V to V _{CC} +0.5V
U/D to GND	0.5V to V _{CC} +0.5V
H to GND	0.5V to V _{CC} +0.5V
L to GND	0.5V to V _{CC} +0.5V
W to GND	0.5V to V _{CC} +0.5V

Operating Ambient Temperature

Industrial ('I' suffix)	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature	65°C to +150°C
Lead Soldering (10 sec max)	+300°C

* Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Absolute Maximum Ratings are limited values applied individually while other parameters are within specified operating conditions, and functional operation at any of these conditions is NOT implied. Device performance and reliability may be impaired by exposure to absolute rating conditions for extended periods of time.

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Test Method	Min	Тур	Max	Units
V _{ZAP} ⁽¹⁾	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			Volts
I _{LTH} ⁽¹⁾⁽²⁾	Latch-Up	JEDEC Standard 17	100			mA
T _{DR}	Data Retention	MIL-STD-883, Test Method 1008	100			Years
N _{END}	Endurance	MIL-STD-883, Test Method 1003	1,000,000			Stores

DC Electrical Characteristics: V_{CC} = +2.5V to +5.5V unless otherwise specified **Power Supply**

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{CC}	Operating Voltage Range		2.5	_	5.5	V
I _{CC1}	Supply Current (Increment)	$V_{CC} = 5.5V, f = 1MHz, I_{W}=0$	_	_	100	μΑ
		$V_{CC} = 5.5V$, $f = 250kHz$, $I_{W}=0$	_	_	50	
ISB ₁ (2)	Supply Current (Standby)	CS=V _{CC} -0.3V	_	_	1	μΑ
		U/D, INC=V _{CC} -0.3V or GND				

Logic Inputs

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{IH}	Input Leakage Current	$V_{IN} = V_{CC}$	_	_	10	μΑ
I _{IL}	Input Leakage Current	$V_{IN} = 0V$	_	_	-10	μΑ
V _{IH1}	TTL High Level Input Voltage	4.5V ≤ V _{CC} ≤ 5.5V	2	_	V _{CC}	V
V _{IL1}	TTL Low Level Input Voltage		0	_	0.8	V
V _{IH2}	CMOS High Level Input Voltage	$2.5V \le V_{CC} \le 5.5V$	V _{CC} x 0.7	_	V _{CC} + 0.3	V
V _{IL2}	CMOS Low Level Input Voltage		-0.3	_	V _{CC} x 0.2	V

3

NOTES: (1) This parameter is tested initially and after a design or process change that affects the parameter.

(2) Latch-up protection is provided for stresses up to 100mA on address and data pins from -1V to V_{CC} + 1V
(3) I_W=source or sink
(4) These parameters are periodically sampled and are not 100% tested.

CAT5115

Potentiometer Parameters

Symbol	Parameter	Conditions	Min	Тур	Max	Units
R _{POT}	Potentiometer Resistance	-10 Device		10		
		-50 Device		50		kΩ
		-00 Device		100		
	Pot Resistance Tolerance				± 20	%
V_{RH}	Voltage on R _H pin		0		Vcc	V
V_{RL}	Voltage on R _L pin		0		Vcc	V
	Resolution			3.2		%
INL	Integral Linearity Error	$I_W \le 2\mu A$		0.5	1	LSB
DNL	Differential Linearity Error	$I_W \le 2\mu A$		0.25	0.5	LSB
Rwi	Wiper Resistance	Vcc = 5V, Iw = 1mA			400	Ω
		$V_{CC} = 2.5V$, $I_W = 1mA$			1	kΩ
l _W	Wiper Current				1	mA
TC _{RPOT}	TC of Pot Resistance			300		ppm/ºC
TC _{RATIO}	Ratiometric TC				20	ppm/ºC
V _N	Noise	100kHz / 1kHz		8/24		nV/√H _z
C _H /C _L /C _W	Potentiometer Capacitances			8/8/25		pF_
fc	Frequency Response	Passive Attenuator, 10kΩ		1.7		MHz

AC CONDITIONS OF TEST

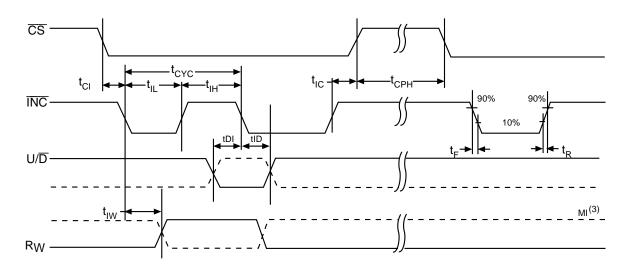
V _{CC} Range	$2.5V \le V_{CC} \le 5.5V$
Input Pulse Levels	0.2V _{CC} to 0.7V _{CC}
Input Rise and Fall Times	10ns
Input Reference Levels	0.5V _{CC}

AC OPERATING CHARACTERISTICS:

 V_{CC} = +2.5V to +5.5V, V_{H} = V_{CC} , V_{L} = 0V, unless otherwise specified

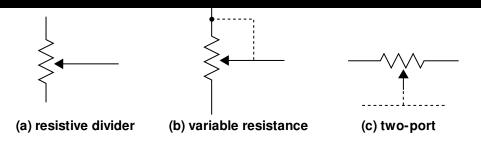
Symbol	Parameter	Min	Typ ⁽¹⁾	Max	Units
t _{Cl}	CS to INC Setup	100	_	_	ns
t _{DI}	U/D to INC Setup	50	_		ns
t _{ID}	U/D to INC Hold	100	_	_	ns
t _{IL}	INC LOW Period	250	_		ns
t _{IH}	INC HIGH Period	250	_	_	ns
t _{IC}	INC Inactive to CS Inactive	1	_		μs
t _{CPH}	CS Deselect Time	100	_		ns
t _{IW}	INC to V _{OUT} Change	_	1	5	μs
t _{CYC}	INC Cycle Time	1	_		μs
t _R , t _F ⁽²⁾	INC Input Rise and Fall Time	_	_	500	μs
t _{PU} ⁽²⁾	Power-up to Wiper Stable	_	_	1	msec

A. C. TIMING

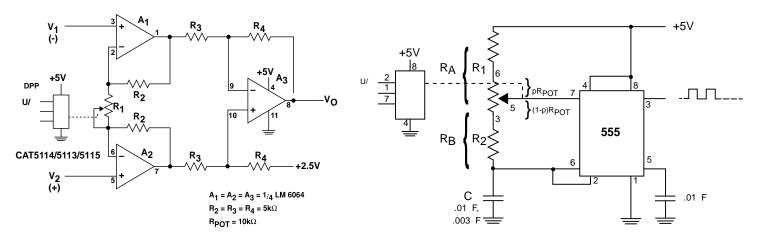


- (1) Typical values are for T_A =25°C and nominal supply voltage. (2) This parameter is periodically sampled and not 100% tested.
- (3) MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.

5

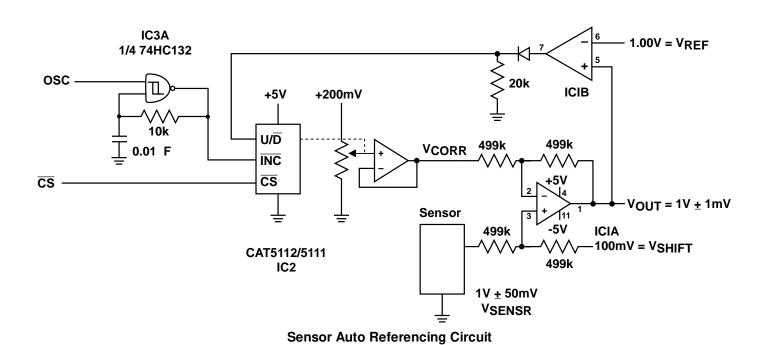


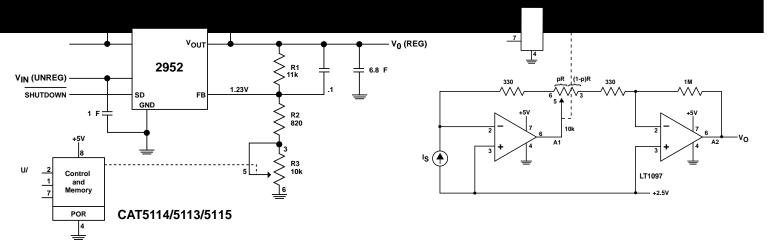
Applications



Programmable Instrumentation Amplifier

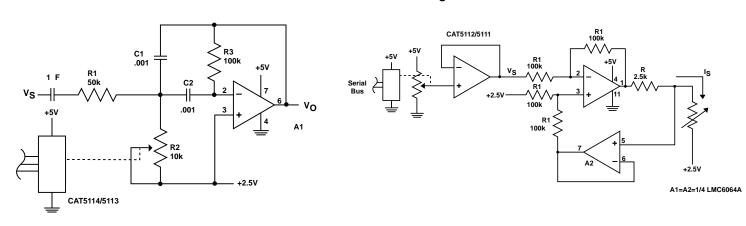
Programmable Sq. Wave Oscillator (555)





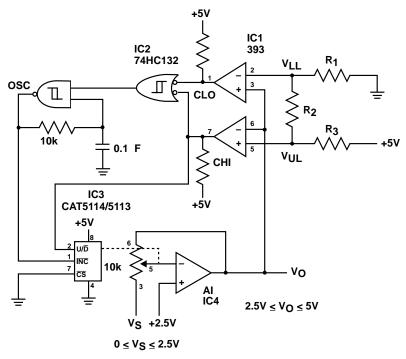
Programmable Voltage Regulator

Programmable I to V convertor



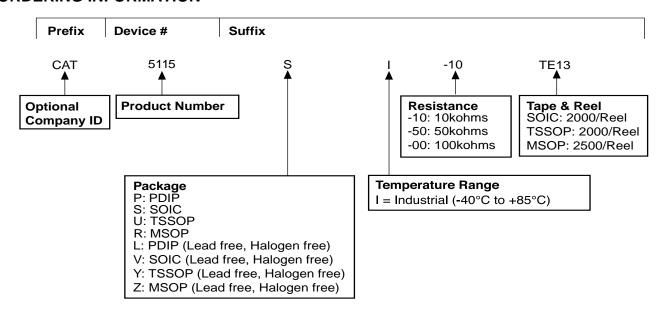
Programmable Bandpass Filter

Programmable Current Source/Sink



Automatic Gain Control

ORDERING INFORMATION



Notes:

(1) The device used in the above example is a CAT5115 SI-10TE13 (SOIC, 10K Ohms, Industrial Temperature, Tape & Reel)

Publication #: 2117

REVISION HISTORY

Date	Rev.	Reason		
9/25/2003	В	Changed designation to Preliminary		
		Updated Description		
		Updated Potentiometer Parameters table		
3/10/2004	С	Updated Potentiometer Parameters table		
3/29/2004	D	Changed Green Package marking for SOIC from W to V		
4/12/2004	Е	Updated Reel Ordering Information		
8/31/2004	F	Deleted ICC2 from DC Characteristics table		
		Updated AC Operating Characteristics table		
		Updated A.C. Timing diagram		

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